NSN 5961-01-362-5395

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View Online at https://aerobasegroup.com/nsn/5961-01-362-5395 **Inclosure Material:** Metal **Overall Length:** 1.240 inches **Overall Height:** Between 0.250 inches and 0.340 inches Overall Width: 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage **Current Rating Per Characteristic:** 15.00 amperes all primaries of standard range and 60.00 amperes collector current, dc any acceptable **Power Rating Per Characteristic:** 70.0 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: